



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Application of	
Yamazaki et al.	I hereby certify that this correspondence is being deposited with the United States Postal Service as first class mail in an envelope addressed to:
Serial No.: 09/841,537	The Assistant Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450 on
Filed: April 24, 2001)	May 2003
For: Semiconductor Device And Method) Of Fabricating Thereof)	Shoon United States of Registered Rep.
Art Unit: 2822)	Signature Date
Examiner: M. Prenty	
Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450	
Sir:	ENT B
Sir: In response to the Office Action dated January 3, 2003, a one month extension of time:	
being separately submitted, please amend the above-identified application as follows.	
	ED 2003 NTER 2800
IN THE CLAIMS:	<u> </u>

IN THE CLAIMS:

Please amend the claims as follows:

Marked-up copy of the claims as amended:

1.(Amended) A semiconductor device comprising:

a thin film transistor comprising a semiconductor layer over a substrate and a gate

electrode with an insulating film interposed therebetween;

a plurality of projected portions over said substrate;